

Surface Mount Switching Diode

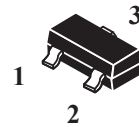
Features:

- *Fast Switching Speed
- *Surface Mount Package Ideally Suited for Automatic Insertion
- *High Conductance
- *For General Purpose Switching Applications

SWITCHING DIODE
225mAMPERS
300VOLTS

Mechanical Data:

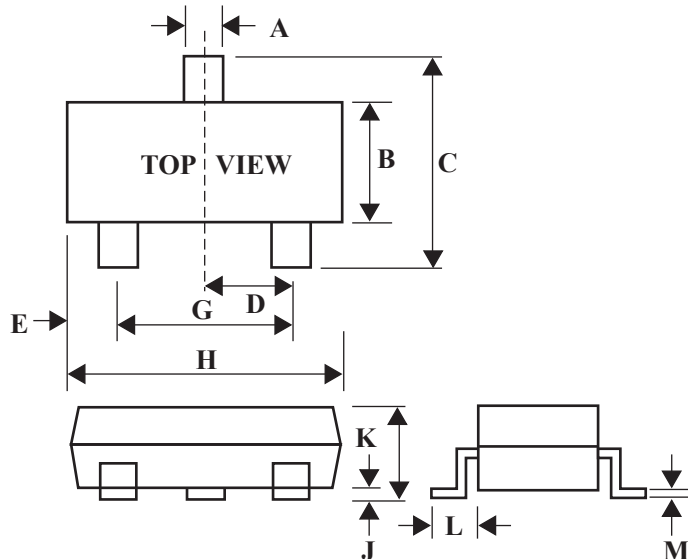
- *Case: SOT-23 Molded Plastic
- *Terminals: Solderable Per MIL-STD-202, Method 208
- *Polarity: See Equivalent Circuit Diagram
- *Weight: 0.008grams(approx)



SOT-23

SOT-23 Outline Dimensions

Unit:mm



Dim	Min	Max
A	0.35	0.51
B	1.19	1.40
C	2.10	3.00
D	0.85	1.05
E	0.46	1.00
G	1.70	2.10
H	2.70	3.10
J	0.01	0.13
K	0.89	1.10
L	0.30	0.61
M	0.076	0.25


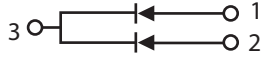
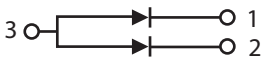
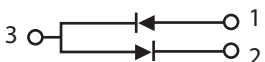
Maximum Ratings ($T_A=25\text{ }^{\circ}\text{C}$ Unless otherwise noted)

Characteristic	Symbol	MMBD2004/C/A/S	Unit
Working Peak Reverse Voltage	VRRM	300	Volts
Peak Repetitive Reverse Voltage	VRWM	240	Volts
DC Blocking Voltage	VR		
Forward Continuous Current	I _F	225	mA
Repetitive Peak Forward Current	I _{FRM}	625	mA
Non-Repetitive Peak Forward Surge Current @t=1.0us @t=1.0s	I _{FSM}	4.0 1.0	A
Power Dissipation	Pd	350	mW
Thermal Resistance Junction to Ambient Air	R _{qJA}	357	K/W
Operating and Storage Temperature Range	T _j , T _{STG}	-65 to +150	°C

Electrical Characteristics ($T_A=25\text{ }^{\circ}\text{C}$ Unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
Reverse Breakdown Voltage I _R =100uA	V _{(BR)R}	300	-	Volts
Forward Voltage I _F =100mA	V _F	-	1.0	Volts
Reverse Leakage @Rated DC Blocking Voltage	I _R	-	100	nAdc
Total Capacitance (V _R =0V, f=1.0MHz)	C _j	-	5.0	Pf
Reverse Recovery Time I _F =I _R =30mA I _{rr} =3.0mA*I _R , RL=100 W	trr		50	nS

Device Marking

Item	Marking	Equivalent Circuit diagram
MMBD2004	DB3	
MMBD2004C	DB4	
MMBD2004A	DB5	
MMBD2004S	DB6	

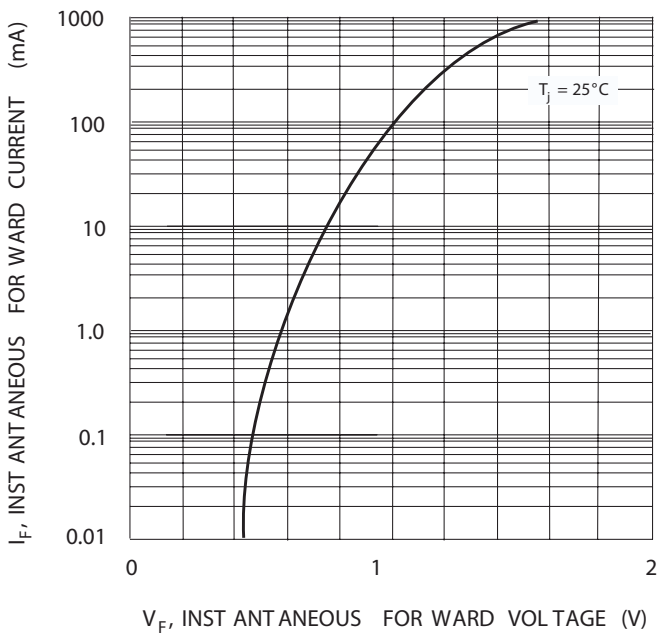


Fig. 1 Forward Characteristics

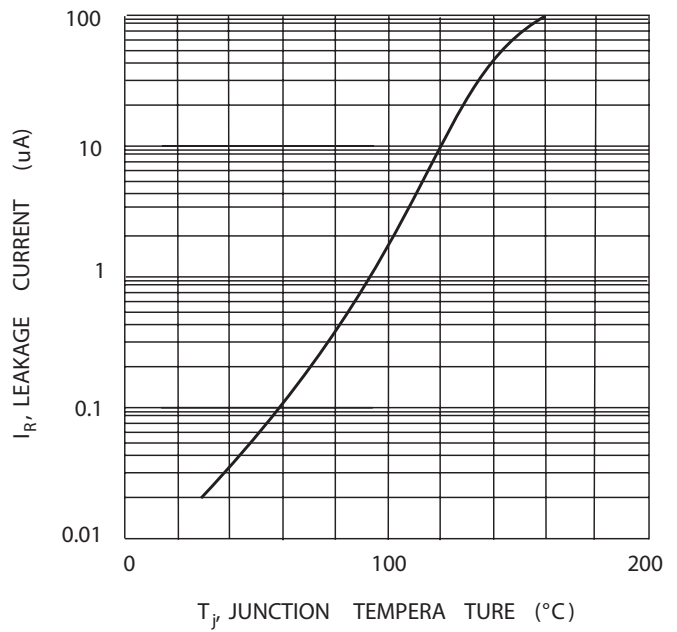


Fig. 2 Leakage Current vs Junction Temperature